NSN 5961-01-032-7930

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-032-7930 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 10.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** 10.00 milliamperes zero-gate-voltage drain current all transistor and 0.70 milliamperes drain current all transistor **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L02320; for navy nuclear propulsion plant products only **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**